

Impurity-induced transition and impurity-enhanced thermopower in the thermoelectric oxide $\text{NaCo}_{2-x}\text{Cu}_x\text{O}_4$

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Various physical quantities are measured and analysed for the Cu-substituted thermoelectric oxide $\text{NaCo}_{2-x}\text{Cu}_x\text{O}_4$. As was previously known, the substituted Cu enhances the thermoelectric power, while it does not increase the resistivity significantly. The susceptibility and the electron specific-heat are substantially decreased with increasing x , which implies that the substituted Cu decreases the effective-mass enhancement. Through a quantitative comparison with the heavy fermion compounds and the valence fluctuation systems, we have found that the Cu substitution effectively increases the coupling between the conduction electron and the magnetic fluctuation. The Cu substitution induces a phase transition at 22 K that is very similar to a spin-density-wave transition.

I. INTRODUCTION

Recently layered cobalt oxides have been extensively investigated as a promising candidate for a thermoelectric material. The thermoelectric material is a material that shows large thermopower (S), low resistivity (ρ) and low thermal conductivity (κ) [1], and a quantity of $Z \equiv S^2/\rho\kappa$ called the figure of merit characterizes the thermoelectric conversion efficiency. Thermoelectric device can generate electric power from heat through the Seebeck effect, and can pump heat through the Peltier effect. Thus far oxides have been regarded as unsuitable for thermoelectric application because of their poor mobility, but some years ago Terasaki *et al.* found that a single crystal of the layered oxide NaCo_2O_4 exhibits good thermoelectric performance [2]. Fujita *et al.* showed that the dimensionless figure of merit ZT of a NaCo_2O_4 single crystal exceeds unity at $T = 1000$ K [3], Ohtaki *et al.* [4] measured $ZT \sim 0.8$ at 1000 K even in the polycrystalline samples of NaCo_2O_4 . Thus this compound is quite promising for thermoelectric power generation at high temperature.

Following NaCo_2O_4 , other layered cobalt oxides, Ca-Co-O [5, 6, 7, 8], Bi-Sr-Co-O [9, 10, 11], Tl-Sr-Co-O [12] have been found to show good thermoelectric performance. In particular, Funahashi *et al.* [8] showed $ZT > 1$ at 1000 K for Ca-Co-O. The most important feature is that the CdI_2 type triangular CoO_2 block is common to the layered cobalt oxides. We have proposed that the high thermoelectric performance of the layered

cobalt oxides cannot be explained by a conventional band picture based on the one-electron approximation, but is understood in terms of the strong electron-electron correlation effects, similarly to the case of heavy-fermion compounds. In fact the material dependence of the thermopower quite resembles that of CeM_2X_2 [13].

A prime example for the difficulties of the one-electron picture is observed in the Cu substitution effects in NaCo_2O_4 [14]. The thermopower of $\text{NaCo}_{2-x}\text{Cu}_x\text{O}_4$ is significantly enhanced, while the resistivity is nearly independent of x . This is quite surprising in comparison with normal impurity effects in a metal. The doped impurity acts as a scattering center in usual cases, and does not make a significant change in thermopower, because it is a quantity of the zero-th order of scattering time. Indeed this is what was observed in high-temperature superconductors [15]. Importantly, correlation effects can explain the large impurity effect on the thermopower, similarly to the case of dilute magnetic alloys [16]. In this paper, we report on measurement of specific heat, susceptibility, Hall coefficient, and transverse magnetoresistance for $\text{NaCo}_{2-x}\text{Cu}_x\text{O}_4$ polycrystalline samples, and discuss the Cu substitution effects quantitatively.

II. EXPERIMENTAL

Polycrystalline samples of $\text{Na}_{1.2}\text{Co}_{2-x}\text{Cu}_x\text{O}_4$ ($x=0, 0.1, 0.2$ and 0.3) were prepared through a solid-state reaction. A stoichiometric amount of Na_2CO_3 , Co_3O_4 and CuO was mixed and calcined at 860°C for 12 h in air. The product was finely ground, pressed into a pellet, and sintered at 920°C for 12 h in air. Since Na tends to evaporate during calcination, we added 20 % excess Na. Namely we expected samples of the nominal composition

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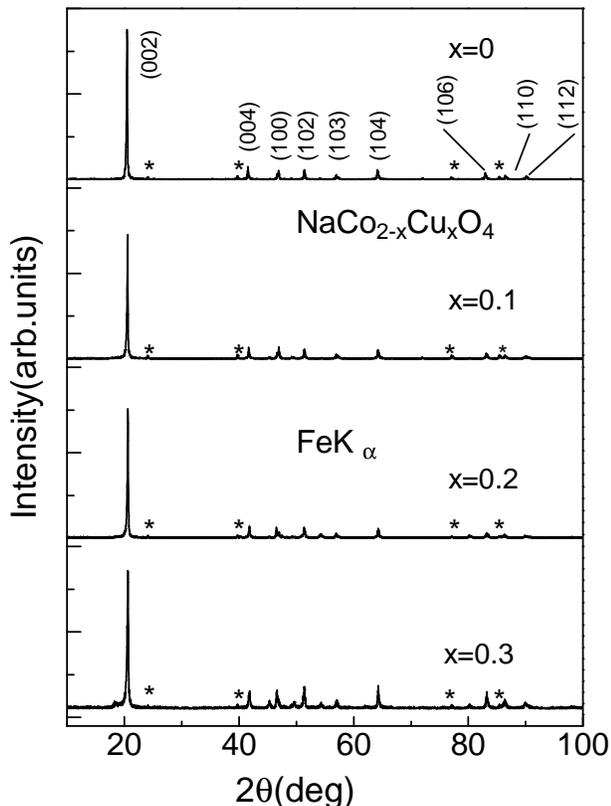


FIG. 1: The x-ray diffraction patterns of the polycrystalline samples of $\text{NaCo}_{2-x}\text{Cu}_x\text{O}_4$. The $\text{Fe K}\alpha$ is used as an x-ray source.

of $\text{Na}_{1.2}\text{Co}_{2-x}\text{Cu}_x\text{O}_4$ to be $\text{NaCo}_{2-x}\text{Cu}_x\text{O}_4$.

The x-ray diffraction (XRD) was measured using a standard diffractometer with $\text{Fe K}\alpha$ radiation as an x-ray source in the $\theta - 2\theta$ scan mode. The resistivity was measured through a four-terminal method, and the thermopower was measured using a steady-state technique with a typical temperature gradient of 0.5 K/cm. The Hall coefficient (R_H) and the transverse magnetoresistance were measured from 15 to 100 K in a closed refrigerator inserted into a room temperature bore of a liquid-He free superconducting magnet. To eliminate the unwanted voltage arising from the misalignment of the voltage pads, the magnetic field was swept from -7 to 7 T with a typical period of 20 min at constant temperatures with a stability of 10 mK. The specific heat was measured using a standard relaxation method with a mechanical heat switch. The mass of the samples used for the measurement is typically 1000 mg and the heat capacity of the samples is always more than two orders of magnitude larger than the addenda heat capacity. The susceptibility was measured with a SQUID susceptometer in a magnetic field of 1 T.

III. RESULTS

Figure 1(a) shows the x-ray diffraction patterns of the prepared samples of $\text{NaCo}_{2-x}\text{Cu}_x\text{O}_4$. Almost all the peaks are indexed as the γ phase [17, 18], though a small amount (approximately less than 5%) of unreacted Co_3O_4 is observed. With increasing Cu content x , no additional peak appears, with the patterns unchanged, which shows that Cu is substituted for Co. However, the sample of $x=0.3$ shows a higher background noise, indicating that the crystal quality becomes worse, possibly owing to the limit of solid solution with Cu.

Figure 2(a) shows the temperature dependence of the resistivity for $\text{NaCo}_{2-x}\text{Cu}_x\text{O}_4$. All the samples are metallic down to 4.2 K without any indication of localization. It should be noted that the increased resistance due to the substituted Cu is of the order of $10\mu\Omega\text{cm}$ for 1 at.% Cu, which is anomalously small in the layered transition-metal oxides [19]. Another important feature is that the resistivity for the Cu substituted samples show a kink near 22 K as indicated by the dotted line. Since the temperature dependence is steeper below 22 K, the density of states (or the carrier concentration) decreases below 22 K.

Figure 2(b) shows the temperature dependence of the thermopower for $\text{NaCo}_{2-x}\text{Cu}_x\text{O}_4$. Thermopower increases with increasing x with a dip near 22 K and a peak

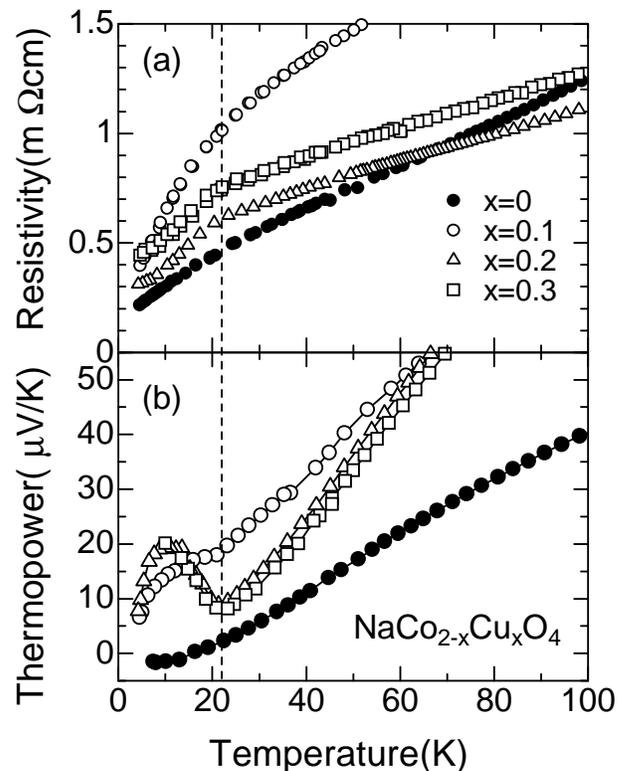


FIG. 2: (a) The resistivity and (b) the thermopower of polycrystalline samples of $\text{NaCo}_{2-x}\text{Cu}_x\text{O}_4$.

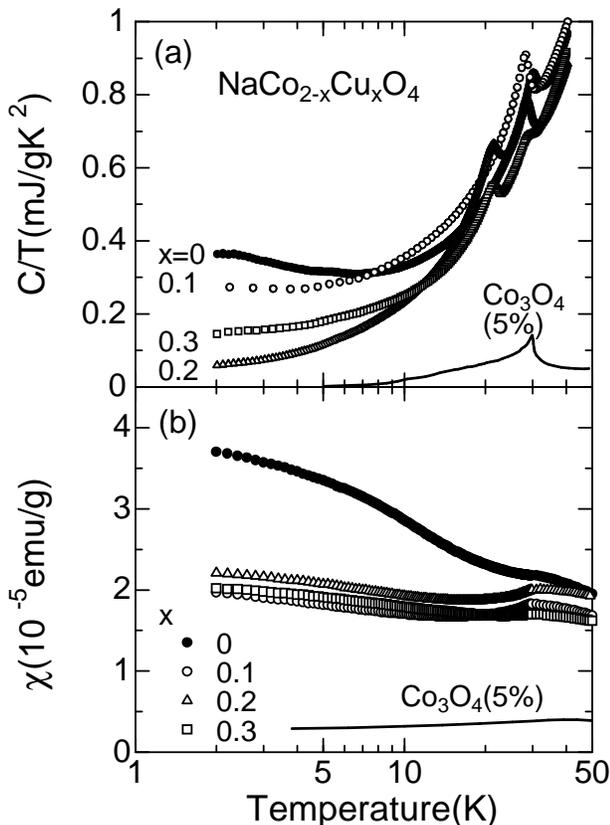


FIG. 3: (a) The specific heat C and (b) the susceptibility χ of polycrystalline samples of $\text{NaCo}_{2-x}\text{Cu}_x\text{O}_4$. Note that C/T is plotted in order to emphasize the electron specific heat coefficient γ . The samples include 5% of unreacted Co_3O_4 , and the data for 5% Co_3O_4 taken from Refs. [20, 21] are plotted by the solid curves.

near 10-15 K. As we previously shown in the analysis for Bi-Sr-Co-O [10], a low-temperature thermopower (S) of the layered Co oxides is determined by the diffusive term that is proportional to temperature (T). Accordingly S/T is an essential parameter similarly to the electron specific-heat coefficient. Thus, the dip, rather than the peak, is a meaningful temperature, which corresponds to the onset of the enhancement in S/T at low temperatures. It should be emphasized that the dip temperature is nearly the same as the kink temperature for the resistivity, which strongly suggests that this temperature is related to a kind of phase transition.

Figure 3(a) shows the specific heat C for $\text{NaCo}_{2-x}\text{Cu}_x\text{O}_4$. In order to emphasize the T -linear electron specific heat, we plot C/T as a function of temperature. As shown in Fig. 3(a), the C/T value at 2 K decreases with increasing the Cu content from 0 to 0.2, which means the decrease of the electron specific heat coefficient γ with x . (For the sample of $x=0.3$, the C/T value increases again, which might be due to an extrinsic origin such as the solid-solution limit of Cu.) Since γ is proportional to the density of states and the

mass-enhancement factor, the present results indicate that the either or both decrease with the Cu substitution. As for high temperatures, all the data show a peak near 30 K which is the antiferromagnetic transition of the unreacted Co_3O_4 , as shown by the solid curve [20]. As mentioned above, the x-ray diffraction patterns reveal less than 5 at.% of unreacted Co_3O_4 , which is consistent with the peak height of the specific heat at 30 K. We should emphasize here that the existence of Co_3O_4 does not seriously affect the estimation of γ , because the C/T value for Co_3O_4 is negligibly small at low temperatures. For $x=0.2$ and 0.3, another peak appears in the specific heat near 22 K, which is close to the kink temperature in ρ , and the dip temperature in S . We thus conclude that the 22-K anomaly comes from a (2nd order) phase transition.

Figure 3(b) shows the susceptibility (χ) of $\text{NaCo}_{2-x}\text{Cu}_x\text{O}_4$. The substituted Cu also decreases the susceptibility, indicating the decrease of the density of states and/or the mass-enhancement factor. A broad hump near 30 K is due to the antiferromagnetic transition of the unreacted Co_3O_4 , as shown by the solid curve [21]. Interestingly, there is no anomaly near 22 K in the susceptibility, suggesting that the transition at 22 K is not the magnetic transition of impurity phases. We further note that the Curie-like contribution is absent in the susceptibility at low temperatures, which shows that magnetic impurities are unlikely to exist other than Co_3O_4 . Quantitatively, the decrease of χ by Cu is more moderate than that of C/T . C/T decreases by a factor of ten from $x=0$ to 0.2, whereas χ decreases only by a factor of two. This implies that the 22-K transition causes a dramatic reduction of the electron entropy possibly owing to a (pseudo)gap formation, while it does not alter the magnetic excitation at $k=0$. The nature of the 22-K transition will be discussed in the next section.

Figure 4(a) shows the Hall coefficient (R_H) of $\text{NaCo}_{2-x}\text{Cu}_x\text{O}_4$. The sign is negative below 100 K, and the magnitude is as small as $4\text{-}6 \times 10^{-4} \text{cm}^3/\text{C}$. The Cu substitution does not change the magnitude so much, indicating that the carrier concentration is nearly unchanged. By contrast, it changes the temperature dependence in a complicated way, which implies that plural kinds of carriers are responsible for the electric conduction. The band calculation by Singh [22] reveals that the two bands of different symmetries cross the Fermi level for NaCo_2O_4 . (See the next section)

Contrary to the Hall effect, the magnetoresistance is weakly dependent on the Cu substitution, as shown in Fig. 4(b). By taking a closer look at the x dependence, one can see that the negative magnetoresistance is gradually suppressed by the substituted Cu. This implies that the kink of the resistivity is more or less smeared against magnetic field, which suggests that the magnetic field suppresses the 22-K transition.

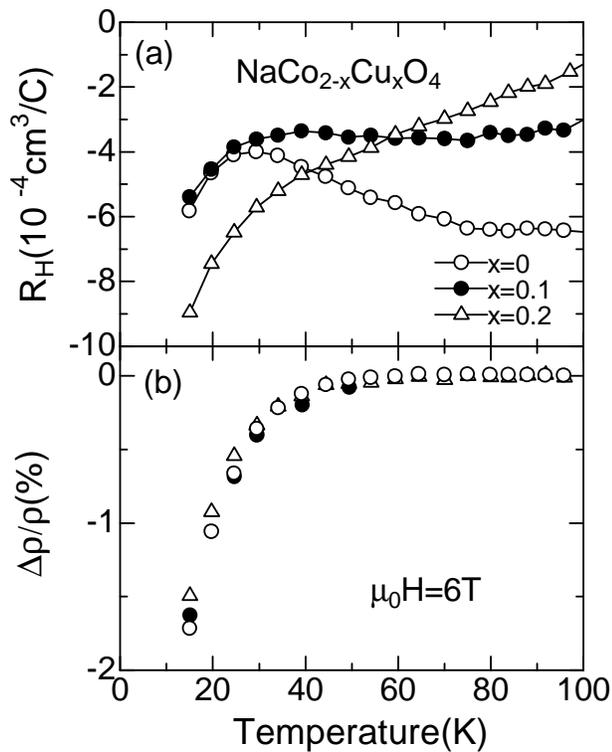


FIG. 4: (a) The Hall coefficient R_H and (b) the magnetoresistance $\Delta\rho/\rho$ of polycrystalline samples of $\text{NaCo}_{2-x}\text{Cu}_x\text{O}_4$.

IV. DISCUSSION

Before going into details, we will begin with a brief review on the electronic states of NaCo_2O_4 . As is well known, the five-fold degenerate d orbitals split into two-fold (e_g) and three-fold (t_{2g}) degenerate levels in an oxygen octahedron. In the real triangular CoO_2 block, the octahedron is compressed along the c direction, and the degeneracy is further quenched, where the lower t_{2g} levels split into e_g and a_{1g} levels. The lower e_g levels correspond to the orbital spread along the CoO_2 block to make a relatively broad band, whilst the a_{1g} orbital is spread along the c direction to make a nearly localized narrow band. Since each Co ion is $3.5+$ with $(3d)^{5.5}$, the highest occupied orbital is a_{1g} in the atomic limit, and the main part of the Fermi surface consists of the narrow a_{1g} band. In the real band calculation, however, there is significant hybridization between the a_{1g} and e_g levels, and the broader $e_g + a_{1g}$ band touches the Fermi level to make small Fermi surfaces [22].

We have proposed that the electronic structure of NaCo_2O_4 is similar to that of the Ce-based intermetallics, a prime example of valence-fluctuation/heavy-fermion compounds [13]. γ and χ of NaCo_2O_4 are as large as those of CePd_3 . In this context, the large thermopower of NaCo_2O_4 is explained in terms of a diffusive contribution of a metal with a heavily enhanced effective mass, and is roughly proportional to γ . In the heavy fermion

compounds, the broad conduction band crosses the Fermi energy, and the narrow (localized) f band is located below the Fermi energy. For NaCo_2O_4 , the broad $e_g + a_{1g}$ band and the narrow a_{1g} band do exist, but both of which cross the Fermi energy to form two kinds of the Fermi surfaces. Thus it is not trivial whether or not the two Fermi surfaces behave heavy-fermion-like in the charge transport. At least we can say that the two Fermi surfaces play different roles, where the Cu substitution induces different effects: ρ is weakly dependent on the Cu content x , whereas S , χ and γ are strongly dependent on x . S , χ and γ are basically proportional to the density of states in the lowest order, which are determined by the large Fermi surface of the a_{1g} symmetry. In contrast, the carriers on the $e_g + a_{1g}$ band can be highly mobile, because it is spread along the in-plane direction. In short, the a_{1g} and $e_g + a_{1g}$ bands are responsible for the large thermopower and a good electric conduction, respectively.

Existence of the a_{1g} and $e_g + a_{1g}$ bands was suggested from the angular dependence of the X-ray absorption spectroscopy experiment [23, 24], where the valence bands of NaCo_2O_4 consist of the a_{1g} and $e_g + a_{1g}$ bands. The valence band of the less conductive Bi-Sr-Co-O is mainly composed only of the a_{1g} band, which is consistent with our speculation that the $e_g + a_{1g}$ band is responsible for the metallic nature of NaCo_2O_4 . The large Fermi surface suggested by the band calculation was not seen in the angle photoemission spectra for Bi-Sr-Co-O , which indicates that the band calculation should be modified by additional effects such as the electron-electron or electron-phonon effects.

A. Phase Transition at 22 K

As shown in the previous section, the Cu substitution causes the phase transition at 22 K, which is probed by the jump of the specific heat, the dip in the thermopower, and the kink in the resistivity. Figure 5(a) shows the specific heat for the $x = 0.2$ sample (the same data in Fig. 3(a)) as a function of temperature in linear scale in order to see the 22-K anomaly clearly. One thing to point out is that the entropy change of this transition is surprisingly small. As shown in Fig. 5(a), we estimated the entropy change by the area surrounded with C/T and the dotted line, which is approximately 77 mJ/Kmol, corresponding to $0.01k_B$ per Co. Actually only 5% of Co_3O_4 impurity exhibits a specific heat jump of the same order at 30 K.

There are two possibilities for the origin of the small entropy change. One is that the 22-K transition is something related to the impurity phase of the order of 1%. Although we cannot exclude this possibility completely, we will take the other possibility that the small entropy change is an intrinsic nature in bulk, because (i) the field dependence of C/T is different between the 22-K transition and the magnetic transition in Co_3O_4 at 30 K as shown in Fig. 5(b), (ii) a possible impurity phase is a Cu-based magnetic material, which is inconsistent with

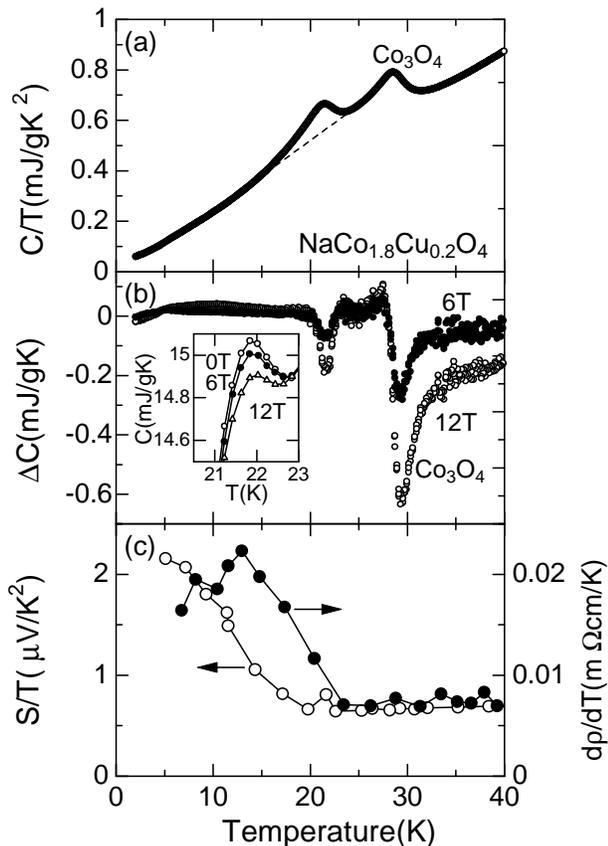


FIG. 5: Phase transition at 22 K for the Cu-substituted sample ($x=0.2$). (a) Specific heat, (b) magneto-specific heat $\Delta C(H) \equiv C(H) - C(0)$, and (c) temperature derivative of the resistivity $d\rho/dT$ and the T-linear coefficient of the thermopower S/T . The inset shows the magnetic field dependence of the specific heat.

no anomaly in χ at 22 K, and (iii) the thermopower and the resistivity systematically change at the same temperature. The most familiar phase transition accompanied by a small entropy change is perhaps superconducting transition. More generally, off-diagonal long range order induces a small entropy change of the order of $Nk_B T/E_F$.

Figure 5(c) shows the T-linear term of the thermopower (S/T) and the temperature derivative of the resistivity $d\rho/dT$, both of which are inversely proportional to the Drude weight [25]. Their temperature dependences are quite similar to each other, where the magnitude increases up to almost twice below 22 K. This indicates that the Drude weight decreases by 50% at low temperatures, implying the existence of a (pseudo)gap. As an off-diagonal long-range order with a gapped state, one would think of charge density wave (CDW) or spin density wave (SDW). The calculated Fermi surface [22] of the a_{1g} band is hexagon-like, which is unstable against CDW or SDW formation with the nesting vector along the Γ -K direction. We think that the 22-K transition is SDW-like, because CDW is insensitive to magnetic field [26]. Actually

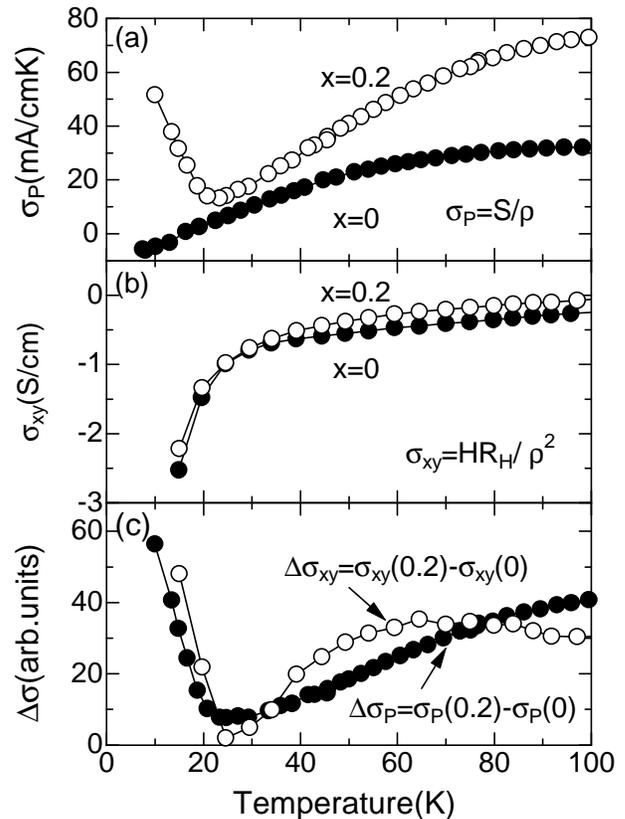


FIG. 6: (a) Peltier conductivity $\sigma_P = S/\rho$ (b) Hall conductivity $\sigma_{xy} = HR_H/\rho^2$ for the $x = 0$ and $x = 0.2$ samples (c) the relative change in σ_P and σ_{xy} from $x = 0$ to 0.2

we can find many similarities between the 22-K transition and SDW transition: The entropy change is observed to be quite small in Cr [27], YbBiPt [28] and $(\text{TMTSF})_2\text{PF}_6$ [29]. The resistivity shows a hump [27, 28], and the thermopower shows a dip at the transition [30].

It is not surprising that the 22-K transition has little effects on the magnetic susceptibility. Since an SDW state is an antiferromagnetically ordered state, the magnetic excitation is gapless in principle. In fact, the SDW state of Cr exhibits a very tiny (1-2%) change in the susceptibility at the transition temperature [27], while it causes a clear hump in the resistivity [31]. The metallic conduction below 22 K, implies that a part (approximately 50%) of the Fermi surface remains, which could smears the SDW transition. To clarify the nature of the transition, a local magnetic probe such as NMR or μSR should be employed.

B. Effects on the Hall coefficient and thermopower

Next we will discuss how we can understand the Cu substitution effects on R_H and S . We should note here that the sum rules of transport parameters for a multi-band system are expressed in the form of conductivities,

not in the form of R_H or S . Let us denote the conductivities for the a_{1g} and $e_g + a_{1g}$ bands as σ^a and σ^e , respectively. The total conductivity σ is then written as

$$\sigma = \sigma^e + \sigma^a \quad (1)$$

Similarly, the total Hall conductivity σ_{xy} and the total Peltier conductivity σ_P are written as

$$\sigma_{xy} = \sigma_{xy}^e + \sigma_{xy}^a \quad (2)$$

$$\sigma_P = \sigma_P^e + \sigma_P^a \quad (3)$$

where the Peltier conductivity [32] is defined as $\sigma_P \equiv S\sigma = S/\rho$.

Figure 6(a) shows the temperature dependence of $\sigma_P = S/\rho$ for $x = 0$ and 0.2 . The Cu substitution enhances the Peltier conductivity over the measured temperature range from 4 to 100 K, indicating that the mobility is enhanced by Cu. The enhancement below 22 K is more remarkable in σ_P than in S , which indicates the mobility is rapidly enhanced below the 22-K transition. Figure 6(b) shows the temperature dependence of $\sigma_{xy} = HR_H/\rho^2$ for $x = 0$ and 0.2 . The complicated change seen in R_H is converted into a simpler change in σ_{xy} . Although the Cu substitution effects in ρ is quite small, $1/\rho^2$ term moderates the difference in R_H . One can see that σ_{xy} is also increased by Cu over the temperature range from 15 to 100 K, as is similar to the case of σ_P .

Let us assume that the substituted Cu affects only the a_{1g} band. Then a difference between $x = 0$ and 0.2 is reduced to a change in σ_P^a and σ_{xy}^a . Figure 6(c) shows $\Delta\sigma_P = \sigma_P(x = 0.2) - \sigma_P(x = 0)$ and $\Delta\sigma_{xy} = \sigma_{xy}(x = 0.2) - \sigma_{xy}(x = 0)$. Most unexpectedly, the change in the Peltier conductivity $\Delta\sigma_P$ and the change in the Hall conductivity $\Delta\sigma_{xy}$ show nearly the same temperature dependence. In particular, a clear enhancement below 22 K indicates that the phase transition causes an equal impact on S and R_H in the form of the Peltier and Hall conductivities.

On the assumption that only the a_{1g} band is modified by Cu, we will consider the change in the a_{1g} band in terms of the carrier concentration n , the effective mass m , and the scattering time τ . Then σ_P^a and σ_{xy}^a are roughly expressed as $\sigma_P^a \sim \langle n/m^* \rangle$ and $\sigma_{xy}^a \sim \langle \tau/m^* \rangle$, where the average of $\langle \dots \rangle$ is defined as $(4\pi^3)^{-1} \int (v_F)^2 \tau \dots d^3k$. A close similarity between $\Delta\sigma_P$ and $\Delta\sigma_{xy}$ implies that $\Delta\langle \tau \rangle$ and $\Delta\langle n \rangle$ are nearly independent of temperature. The T -independent $\Delta\langle \tau \rangle$ means the scattering time averaged in the a_{1g} Fermi surface is dominated by impurity scattering, which is consistent with the localized picture of the a_{1g} band. The positive values of $\Delta\sigma_{xy}$ and $\Delta\sigma_P$ suggests that the increase of $\langle 1/m^* \rangle$. This indicates that the mass enhancement is suppressed (the mobility is enhanced) by Cu over the measured temperature range, regardless of the 22-K transition, which is consistent with the decrease in γ and χ by Cu.

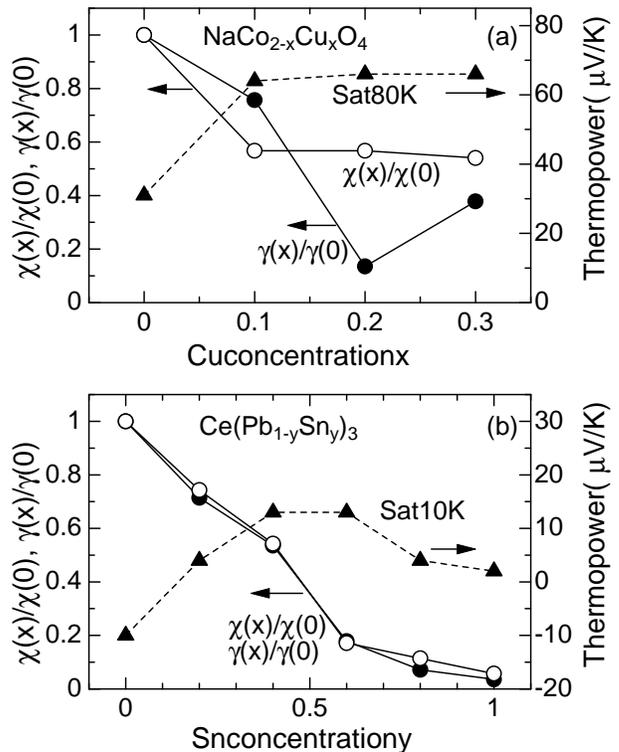


FIG. 7: (a) Cu dependence of χ , γ and S of $\text{NaCo}_{2-x}\text{Cu}_x\text{O}_4$. (b) Sn dependence of χ , γ and S of $\text{Ce}(\text{Pb}_{1-y}\text{Sn}_y)_3$.

C. Comparison with Ce based compounds

Based on the heavy-fermion scenario, it seems inconsistent that the substituted Cu causes the decrease in γ (Fig. 3) together with the increase in S (Fig. 2). As shown in Fig. 7(a), γ , χ and S are plotted as a function of the Cu content x . (Note that γ was estimated as C/T at 2 K, and χ was estimated as the raw value of χ at 2 K.) Although γ and χ decrease with x , S significantly increases with x , where $S \propto \gamma$ is no longer valid.

We should emphasize that the relationship between γ and S is complicated also in the Ce-based compounds. Figure 7(b) shows γ , χ [33] and S [34] for $\text{Ce}(\text{Pb}_{1-y}\text{Sn}_y)_3$ as a function of the Sn content y . CePb_3 is in the heavy fermion regime (low Kondo temperature) and CeSn_3 is in the valence fluctuation regime (high Kondo temperature). Thus the solid solution between Pb and Sn changes the material from the heavy-fermion to the valence-fluctuation compound, which is evidenced by the fact that χ and γ monotonically decrease with y . On the other hand, S exhibits complicated y dependence. S is negative for $y = 0$, increases with y up to 0.4, and eventually decreases from $y=0.6$ to 1.0.

This is intuitively understood as follows. When the Kondo temperature is sufficiently low as in the case of CePb_3 , the RKKY interaction survives at low temperatures, and often causes a magnetic transition. Since

the magnetic transition release the entropy of the spin sector, the entropy per carrier (equivalently the diffusive term of the thermopower) would be suppressed against the fluctuation of the magnetic transition. On the other hand, when the Kondo temperature is high enough, the mass enhancement is severely suppressed to give a small thermopower again. Thus the thermopower would take a maximum at an intermediate value of the Kondo temperature. This is indeed what we see in Fig. 7(b), and similar to the general trend of the 20-K thermopower of CeM_2X_2 found by Jaccard *et al.*[35]

In this context, the NaCo_2O_4 is located near the heavy-fermion regime, and the substituted Cu caused the decrease in the mass enhancement accompanied by the increase in S , which is consistent with the increase in the Peltier and Hall conductivities seen in the previous subsection. Although there is no microscopic relationship between $\text{NaCo}_{2-x}\text{Cu}_x\text{O}_4$ and $\text{Ce}(\text{Pb}_{1-y}\text{Sn}_y)_3$, a close resemblance in Fig. 7 suggests that the unsubstituted NaCo_2O_4 corresponds to $y \sim 0.2$, while $\text{NaCo}_{1.8}\text{Cu}_{0.2}\text{O}_4$ corresponds to $y \sim 0.4-0.6$. We further note that the Pd substituted NaCo_2O_4 shows *negative* thermopower below 50 K, which might correspond to $y < 0.2$ [36].

D. Order from disorder

Although the microscopic theory for the high thermoelectric performance of NaCo_2O_4 is still lacking, the following features are established. (1) The mixture of Co^{3+} and Co^{4+} in the low spin state can carry a large entropy of $k_B \log 6$ [37]. (2) NaCo_2O_4 shows no structural, electric, and magnetic transitions from 2 to 1000 K [3, 4]. (3) From (1)(2), the large entropy cannot be released through phase transitions, and inevitably adhere to the conducting carriers to form a “heavy-fermion”-like electron.

In this respect, NaCo_2O_4 is very close to the instability for various phase transitions arising from the large entropy per site. The Cu substitution enhances the instability, and eventually causes the SDW-like transition at 22 K. This type of transition is called “order from disorder” [38], which has been extensively investigated experimentally as well as theoretically. In other words, instabilities against various phases are competing or disordering in NaCo_2O_4 , and any phase transitions are prohibited down to low temperatures. This does not mean that NaCo_2O_4 is far from the instability of phase transitions, but rather, is very susceptible to various transitions against various perturbations. In fact, $\text{Na}_{1.5}\text{Co}_2\text{O}_4$ exhibits a glassy behavior at 3 K due to structure instability of the γ phase [39], and $(\text{Bi,Pb})\text{-Sr-Co-O}$ shows a ferromagnetic transition at 4 K due to the lattice misfit [40].

Among various possible transitions, it is not trivial whether an SDW-like state is favored by impurities or not. As an SDW-formation mechanism, we should note here that SDW and CDW are closely related to the nest-

ing of the and the topology of the Fermi surface. They are a property for a metal, and occur when the correlation effect is weak enough to hold one-electron picture based on the band calculation. As often mentioned in the present paper, the experimental results consistently suggest that Cu suppresses the mass enhancement without significant change in the carrier concentration. If so, the decrease in χ implies that the substituted Cu enhances the screening of the magnetic fluctuation, which might recover the band picture to cause the CDW/SDW instability of the a_{1g} Fermi surface.

V. SUMMARY AND FUTURE ISSUES

In this article, we have discussed the Cu substitution effects on the thermoelectric and thermodynamic properties of $\text{NaCo}_{2-x}\text{Cu}_x\text{O}_4$. The substituted Cu induces a phase transition at 22 K, which is characterized by the kink in the resistivity, the hump in the thermopower, and the jump in the specific heat. We have analysed the nature of the transition, and finally proposed a spin-density-wave-like state as a possible origin, because (i) it accompanies a small entropy change of the order of $10^{-2}k_B$ per Co, (ii) the transition is sensitive to the magnetic field, (iii) the large Fermi surface of the a_{1g} character is gapped. The impurity induced transition is often called “order from disorder”, which implies that phase transitions are somehow suppressed in the unsubstituted NaCo_2O_4 .

Above the transition temperature, the thermoelectric properties are at least qualitatively compared with those of heavy-fermions valence-fluctuation compounds, where mobile holes on the $e_g + a_{1g}$ band and the nearly localized holes of the a_{1g} band correspond to the carrier and the f electrons. In this analogy, the substituted Cu increase the interaction between the $e_g + a_{1g}$ and a_{1g} bands to decrease the effective-mass enhancement.

In this article we have reviewed the phenomenology of the Cu substitution effects, but failed to address the microscopic origin and/or the electronic states of the substituted Cu. This is because our experiments were concerned only with the thermodynamic and transport properties of bulk materials. Nonetheless we can say that the scattering cross section will be small for the $d_{x^2-y^2}$ and d_{z^2} levels of the impurity in NaCo_2O_4 , because the valence bands of NaCo_2O_4 consist of t_{2g} . Thus the substituted Cu (possibly divalent [41]) will not increase ρ seriously, because Cu^{2+} has the highest occupied orbital of $d_{x^2-y^2}$ that is orthogonal to t_{2g} . In addition, strong Jahn-Teller effects of Cu^{2+} may cause local distortion of the CoO_2 block, which serves as a kind of chemical pressure to increase S [13]. To proceed further, site-selective probes such as NMR, photoemission, and STM/STS should be employed.

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